

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	476	331/117D.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/08 11:42
2	BRS	L2	1391	331/117r.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/08 11:48
3	BRS	L3	751	(semiconductor and resonant and transmission and line and (reactance or induct\$4 or capacit\$4) and diode and oscillat\$4)	US-PGPUB	2006/05/08 11:50
4	BRS	L4	4	(semiconductor and resonant and transmission and line and (reactance or induct\$4 or capacit\$4) and diode and oscillat\$4).clm.	US-PGPUB	2006/05/08 11:52
5	BRS	L5	263	331/107sl.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/08 11:57
6	BRS	L6	2163	333/33.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/08 11:58
7	BRS	L7	1371	333/32.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/08 11:58